## NSN 5961-01-315-7167

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## Inclosure Material:

Metal

**Overall Length:** 

0.260 inches

## Terminal Length:

0.500 inches

## **Overall Diameter:**

0.370 inches

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-5

Electrode Internally-electrically Connected To Case:

#### Collector

**Mounting Method:** 

Terminal

## Terminal Circle Diameter:

0.200 inches

#### **Features Provided:**

Hermetically sealed case and quality assurance level tx

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector-to-emitter, resistance between base and emitter and 7.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

3.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

300.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

3 uninsulated wire lead

## Specification Data:

81349-mil-s-19500/225 government specification

## Shelf Life:

NI/o

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Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

Fiig:

A110a0

